

Ceramic Surface Mount TCXO CMOS or Clipped Sine Output

* Fast Delivery

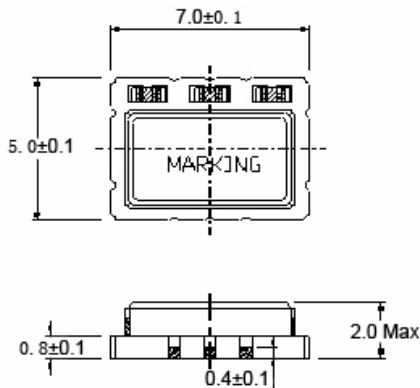
Applications

- * Communications
- * Routers
- * Switches
- * WAN Interfaces
- * Aerospace
- * Military/Space

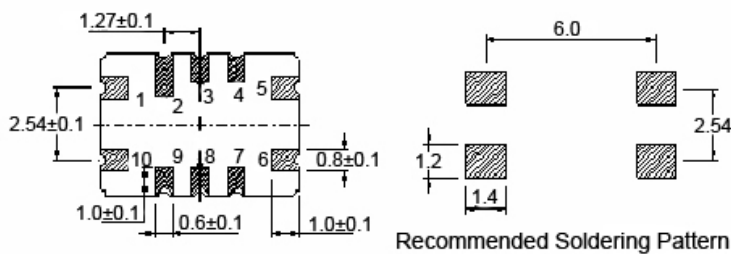


Part Numbering Example: **MGT GEA C - XX.XXXX M**

MGT	G	E	A	C		22.5792M
SERIES	OPERATING TEMP.	VOLTAGE	STABILITY	OUTPUT	GRADE	FREQUENCY
	D=-30°C ~ +75°C G=-40°C ~ +85°C	E = 3.3V D = 5.0V	A = ± 5.0 ppm B = ± 8.0 ppm	C=CMOS N=Clipped Sine	Blank =Industrial M=MIL-STD-883B	1.500 ~200.00 MHz



PIN	Specification
1	Vcontrol or NC
5	GND
6	Output
10	Vcc



Environmental and Mechanical

Parameter	Specification
Mechanical Shock	Per MIL-STD-202, Method 213, Condition E
Thermal Shock	Per MIL-STD-883, Method 1011, Condition A
Vibration	Per MIL-STD-883, Method 2007, Condition A
Soldering Conditions	260°C for 10s max
Hermetic Seal	Leak rate less than 5×10^{-8} atm.cc/s of helium (crystal only)

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Features

Frequency range of 5MHz to 26MHz
Fundamental mode crystal
High Reliability in accordance with MIL-STD-883B
Low power consumption

Parameter	Symbol	Condition	Min	Typ	Max	Unit	Note
Frequency Range	F		1.5		200	MHz	
Frequency Stability	$\Delta F/F$	Vs. Operating Temperature Initial Tolerance Vs. Supply Voltage Vs. Aging over 20 Years Vs. Load 15pF $\pm$ 10%			± 0.2 ± 4.6	ppm	Total Inclusive Over 20 years
Operating Temperature Range	T		0 -40		+70 +85	°C	Order Code B Order Code G
Supply Voltage	Vcc		4.75 3.13	5.00 3.30	5.25 3.47	V	Order Code D Order Code E
CMOS Supply Current	Ic				6	mA	
Clipped Sine Supply Current	Ic				3.5		
Voltage Control	Vc	For 3.3V model For 5.0V model	0 0.5		3.3 4.5	V	
Vc Input Impedance			100K			Ω	
APR		APR inclusive of aging over 20 years.	5			ppm	See Ordering Information
Deviation slope		Monotonic positive					
Linearity			-10		+10	ppm/V	
Modulation BW			10			KHz	3dB BW
SSB Phase Noise		@ 100Hz @ 1 KHz @10 KHz		-120 -140 -148		dBc/Hz	Fo=12.8MHz
Phase Jitter		1s over 12Khz ~ 20MHz			3.5	ps	Fo=12.8MHz
Start up					2	ms	
CMOS Output Level	Voh Vol	15pF 50% $\pm$ 5 symmetry	90%Vcc		10%Vcc	V	
Clipped Sine Output Level		@10KO // 10pF	0.8			Vp-p	
Rise/Fall Time					8	ms	
Storage Temp.			-55		+125	°C	